

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L89	7	I81 and (aluminum near10 bottom)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 12:30
L90	21	I81 and ((al or aluminum) near10 bottom)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 12:34
L91	20	I81 and ((al or aluminum) near10 (lowest or bottommost or first or bottom)) and ((tin or (titanium adj nitride)) near10 (top or topmost or highest or third))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:01
L92	155	I81 and (active adj matrix)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:01
L93	150	I81 and (active adj matrix) and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:01
L94	21	I81 and (active adj matrix) and (tft or (thin near film near transistor)) and ((scan or scanning)) and (common near line)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:04
L95	18	I81 and (active adj matrix) and (tft or (thin near film near transistor)) and ((scan or scanning)) and (common near line) and nitrogen	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:05
L96	19	I81 and (active adj matrix) and (tft or (thin near film near transistor)) and ((scan or scanning or signal) near line) and (common near line) and nitrogen	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:06
L97	15	I81 and (active adj matrix) and (tft or (thin near film near transistor)) and ((scan or scanning or signal) near line) and ((tin or (titanium adj nitride)) with nitrogen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:07

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L98	53	I81 and (active adj matrix) and (tft or (thin near film near transistor)) and ((scan or scanning or signal) near line) and (((tin or (titanium adj nitride))) same (al or aluminum))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:08
L99	50	I81 and (active adj matrix) and (tft or (thin near film near transistor)) and ((scan or scanning or signal) near line) and (((tin or (titanium adj nitride))) same (al or aluminum)) and (pixel adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:09
L100	26	I81 and (active adj matrix) and (tft or (thin near film near transistor)) and ((scan or scanning or signal) near line) and (((tin or (titanium adj nitride))) same (al or aluminum)) and (pixel adj electrode).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:09
L101	16	I81 and (active adj matrix) and (tft or (thin near film near transistor)) and ((scan or scanning or signal) near line).clm. and (((tin or (titanium adj nitride))) same (al or aluminum)) and (pixel adj electrode).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:10
L102	5	I81 and (active adj matrix).clm. and (tft or (thin near film near transistor)).clm. and ((scan or scanning or signal) near line).clm. and (((tin or (titanium adj nitride))) same (al or aluminum)) and (pixel adj electrode).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:11
L103	41	(active adj matrix).clm. and (tft or (thin near film near transistor)).clm. and ((scan or scanning or signal) near line).clm. and (((tin or (titanium adj nitride))) same (al or aluminum)) and (pixel adj electrode).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:12
L104	27	(active adj matrix).clm. and (tft or (thin near film near transistor)).clm. and ((scan or scanning or signal) near line).clm. and (((tin or (titanium adj nitride))) with (al or aluminum)) and (pixel adj electrode).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:13

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L105	2	(active adj matrix).clm. and (tft or (thin near film near transistor)).clm. and ((scan or scanning or signal) near line).clm. and (((tin or (titanium adj nitride))) with (al or aluminum) with ((first or second or third or upper or lower or top or bottom or middle or three or four) near (layer or film))) and (pixel adj electrode).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:15
L106	38	(active adj matrix) and (tft or (thin near film near transistor)).clm. and ((scan or scanning or signal) near line).clm. and (((tin or (titanium adj nitride))) with (al or aluminum) with ((first or second or third or upper or lower or top or bottom or middle or three or four) near (layer or film))) and (pixel adj electrode).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/26 13:18